

# DATA SHEET

## **74LVC2G04** Dual inverter

Product specification  
Supersedes data of 2003 Jul 22

2004 Sep 15

**Dual inverter****74LVC2G04****FEATURES**

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - HBM EIA/JESD22-A114-B exceeds 2000 V
  - MM EIA/JESD22-A115-A exceeds 200 V.
- $\pm 24$  mA output drive ( $V_{CC} = 3.0$  V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Multiple package options
- Specified from  $-40$  °C to  $+85$  °C and  
 $-40$  °C to  $+125$  °C.

**QUICK REFERENCE DATA**GND = 0 V;  $T_{amb} = 25$  °C.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
$t_{PHL}/t_{PLH}$	propagation delay inputs nA to outputs nY	$V_{CC} = 1.8$ V; $C_L = 30$ pF; $R_L = 1$ kΩ	3.5	ns
		$V_{CC} = 2.5$ V; $C_L = 30$ pF; $R_L = 500$ Ω	2.2	ns
		$V_{CC} = 2.7$ V; $C_L = 50$ pF; $R_L = 500$ Ω	2.7	ns
		$V_{CC} = 3.3$ V; $C_L = 50$ pF; $R_L = 500$ Ω	2.7	ns
		$V_{CC} = 5.0$ V; $C_L = 50$ pF; $R_L = 500$ Ω	1.9	ns
$C_I$	input capacitance		2.5	pF
$C_{PD}$	power dissipation capacitance per gate	$V_{CC} = 3.3$ V; notes 1 and 2	13.5	pF

**Notes**

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in Volts;

N = total load switching outputs;

$\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

2. The condition is  $V_I = \text{GND}$  to  $V_{CC}$ .

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**FUNCTION TABLE**

See note 1.

INPUT	OUTPUT
nA	nY
L	H
H	L

**Note**

1. H = HIGH voltage level;  
L = LOW voltage level.

**ORDERING INFORMATION**

TYPE NUMBER	PACKAGE					
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	MARKING
74LVC2G04GW	-40 °C to +125 °C	6	SC-88	plastic	SOT363	V4
74LVC2G04GV	-40 °C to +125 °C	6	SC-74	plastic	SOT457	V04
74LVC2G04GM	-40 °C to +125 °C	6	XSON6	plastic	SOT886	V4

**PINNING**

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	GND	ground (0 V)
3	2A	data input
4	2Y	data output
5	V <sub>CC</sub>	supply voltage
6	1Y	data output

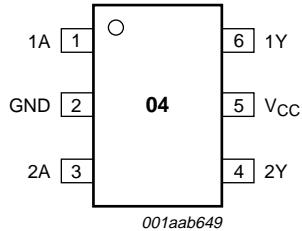
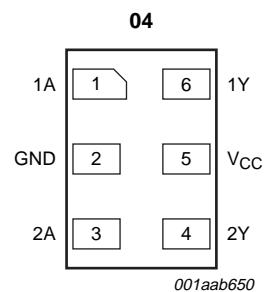


Fig.1 Pin configuration SC-88 and SC-74.



Transparent top view

Fig.2 Pin configuration XSON6.

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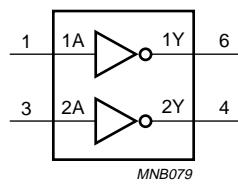


Fig.3 Logic symbol.

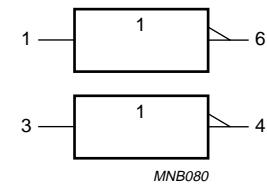


Fig.4 IEE/IEC logic symbol.

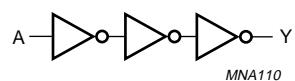


Fig.5 Logic diagram (one driver).

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## RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CC}$	supply voltage		1.65	5.5	V
$V_I$	input voltage		0	5.5	V
$V_O$	output voltage	active mode	0	$V_{CC}$	V
		$V_{CC} = 0$ V; Power-down mode	0	5.5	V
$T_{amb}$	operating ambient temperature		-40	+125	°C
$t_r, t_f$	input rise and fall times	$V_{CC} = 1.65$ V to 2.7 V	0	20	ns/V
		$V_{CC} = 2.7$ V to 5.5 V	0	10	ns/V

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CC}$	supply voltage		-0.5	+6.5	V
$I_{IK}$	input diode current	$V_I < 0$ V	-	-50	mA
$V_I$	input voltage	note 1	-0.5	+6.5	V
$I_{OK}$	output diode current	$V_O > V_{CC}$ or $V_O < 0$ V	-	$\pm 50$	mA
$V_O$	output voltage	active mode; notes 1 and 2	-0.5	$V_{CC} + 0.5$	V
		Power-down mode; notes 1 and 2	-0.5	+6.5	V
$I_O$	output source or sink current	$V_O = 0$ V to $V_{CC}$	-	$\pm 50$	mA
$I_{CC}, I_{GND}$	$V_{CC}$ or GND current		-	$\pm 100$	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_D$	power dissipation	$T_{amb} = -40$ °C to +125 °C	-	300	mW

## Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. When  $V_{CC} = 0$  V (Power-down mode), the output voltage can be 5.5 V in normal operation.

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**DC CHARACTERISTICS**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. <sup>(1)</sup>	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		1.65 to 1.95	0.65 × V <sub>CC</sub>	—	—	V
			2.3 to 2.7	1.7	—	—	V
			2.7 to 3.6	2.0	—	—	V
			4.5 to 5.5	0.7 × V <sub>CC</sub>	—	—	V
V <sub>IL</sub>	LOW-level input voltage		1.65 to 1.95	—	—	0.35 × V <sub>CC</sub>	V
			2.3 to 2.7	—	—	0.7	V
			2.7 to 3.6	—	—	0.8	V
			4.5 to 5.5	—	—	0.3 × V <sub>CC</sub>	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		I <sub>O</sub> = 100 µA	1.65 to 5.5	—	—	0.1	V
		I <sub>O</sub> = 4 mA	1.65	—	—	0.45	V
		I <sub>O</sub> = 8 mA	2.3	—	—	0.3	V
		I <sub>O</sub> = 12 mA	2.7	—	—	0.4	V
		I <sub>O</sub> = 24 mA	3.0	—	—	0.55	V
		I <sub>O</sub> = 32 mA	4.5	—	—	0.55	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		I <sub>O</sub> = -100 µA	1.65 to 5.5	V <sub>CC</sub> - 0.1	—	—	V
		I <sub>O</sub> = -4 mA	1.65	1.2	—	—	V
		I <sub>O</sub> = -8 mA	2.3	1.9	—	—	V
		I <sub>O</sub> = -12 mA	2.7	2.2	—	—	V
		I <sub>O</sub> = -24 mA	3.0	2.3	—	—	V
		I <sub>O</sub> = -32 mA	4.5	3.8	—	—	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND	5.5	—	±0.1	±5	µA
I <sub>off</sub>	power OFF leakage current	V <sub>I</sub> or V <sub>O</sub> = 5.5 V	0	—	±0.1	±10	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	5.5	—	0.1	10	µA
ΔI <sub>CC</sub>	additional quiescent supply current per pin	V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A	2.3 to 5.5	—	5	500	µA

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<b>SYMBOL</b>	<b>PARAMETER</b>	<b>TEST CONDITIONS</b>		<b>MIN.</b>	<b>TYP.<sup>(1)</sup></b>	<b>MAX.</b>	<b>UNIT</b>
		<b>OTHER</b>	<b>V<sub>CC</sub> (V)</b>				
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		1.65 to 1.95	0.65 × V <sub>CC</sub>	—	—	V
			2.3 to 2.7	1.7	—	—	V
			2.7 to 3.6	2.0	—	—	V
			4.5 to 5.5	0.7 × V <sub>CC</sub>	—	—	V
V <sub>IL</sub>	LOW-level input voltage		1.65 to 1.95	—	—	0.35 × V <sub>CC</sub>	V
			2.3 to 2.7	—	—	0.7	V
			2.7 to 3.6	—	—	0.8	V
			4.5 to 5.5	—	—	0.3 × V <sub>CC</sub>	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	1.65 to 5.5	—	—	0.1	V
		I <sub>O</sub> = 100 µA				0.70	V
		I <sub>O</sub> = 4 mA				0.45	V
		I <sub>O</sub> = 8 mA				0.60	V
		I <sub>O</sub> = 12 mA				0.80	V
		I <sub>O</sub> = 24 mA				0.80	V
		I <sub>O</sub> = 32 mA				0.80	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	1.65 to 5.5	V <sub>CC</sub> – 0.1	—	—	V
		I <sub>O</sub> = -100 µA				—	V
		I <sub>O</sub> = -4 mA				—	V
		I <sub>O</sub> = -8 mA				—	V
		I <sub>O</sub> = -12 mA				—	V
		I <sub>O</sub> = -24 mA				—	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND	5.5	—	—	±20	µA
I <sub>off</sub>	power OFF leakage current	V <sub>I</sub> or V <sub>O</sub> = 5.5 V	0	—	—	±20	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	5.5	—	—	40	µA
ΔI <sub>CC</sub>	additional quiescent supply current per pin	V <sub>I</sub> = V <sub>CC</sub> – 0.6 V; I <sub>O</sub> = 0 A	2.3 to 5.5	—	—	5000	µA

**Note**

1. All typical values are measured at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C.

## Dual inverter

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## AC CHARACTERISTICS

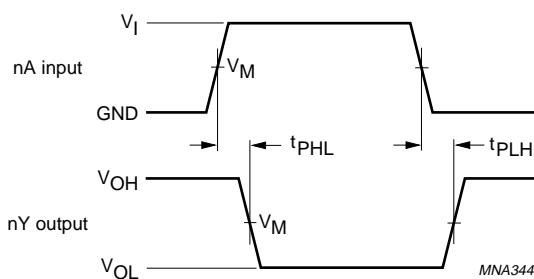
GND = 0 V.

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. <sup>(1)</sup>	MAX.	UNIT
		WAVEFORMS	V <sub>cc</sub> (V)				
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>							
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay nA to nY	see Figs 6 and 7	1.65 to 1.95	1.0	3.5	8.0	ns
			2.3 to 2.7	1.0	2.2	4.4	ns
			2.7	1.0	2.7	5.2	ns
			3.0 to 3.6	0.5	2.7	4.1	ns
			4.5 to 5.5	1.0	1.9	3.2	ns
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>							
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay nA to nY	see Figs 6 and 7	1.65 to 1.95	1.0	-	9.5	ns
			2.3 to 2.7	1.0	-	5.4	ns
			2.7	1.0	-	7.0	ns
			3.0 to 3.6	0.5	-	5.5	ns
			4.5 to 5.5	1.0	-	3.8	ns

## Note

1. All typical values are measured at T<sub>amb</sub> = 25 °C.

## AC WAVEFORMS



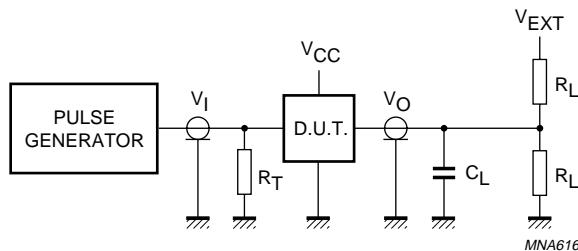
V <sub>CC</sub>	V <sub>M</sub>	INPUT	
		V <sub>I</sub>	t <sub>r</sub> = t <sub>f</sub>
1.65 V to 1.95 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 2.0 ns
2.3 V to 2.7 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 2.0 ns
2.7 V	1.5 V	2.7 V	≤ 2.5 ns
3.0 V to 3.6 V	1.5 V	2.7 V	≤ 2.5 ns
4.5 V to 5.5 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 2.5 ns

V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage drop that occur with the output load.

Fig.6 Input nA to output nY propagation delay times.

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$V_{CC}$	$V_I$	$C_L$	$R_L$	$V_{EXT}$
				$t_{PLH}/t_{PHL}$
1.65 V to 1.95 V	$V_{CC}$	30 pF	1 k $\Omega$	open
2.3 V to 2.7 V	$V_{CC}$	30 pF	500 $\Omega$	open
2.7 V	2.7 V	50 pF	500 $\Omega$	open
3.0 V to 3.6 V	2.7 V	50 pF	500 $\Omega$	open
4.5 V to 5.5 V	$V_{CC}$	50 pF	500 $\Omega$	open

Definitions for test circuit:

$R_L$  = Load resistor.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

Fig.7 Load circuitry for switching times.

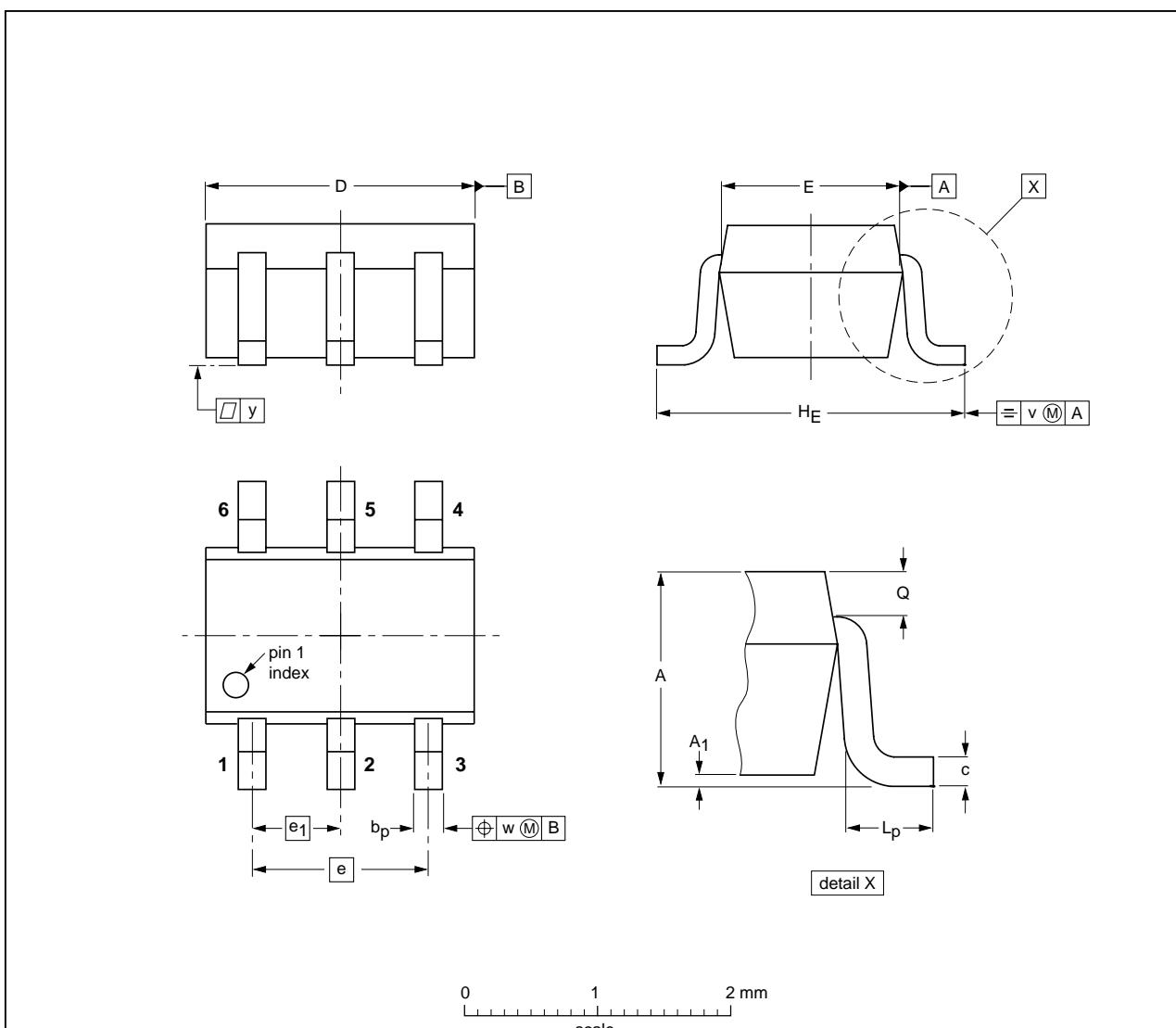
## Dual inverter

74LVC2G04

## PACKAGE OUTLINES

Plastic surface mounted package; 6 leads

SOT363



## DIMENSIONS (mm are the original dimensions)

UNIT	A	A <sub>1</sub> max	b <sub>p</sub>	c	D	E	e	e <sub>1</sub>	H <sub>E</sub>	L <sub>p</sub>	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

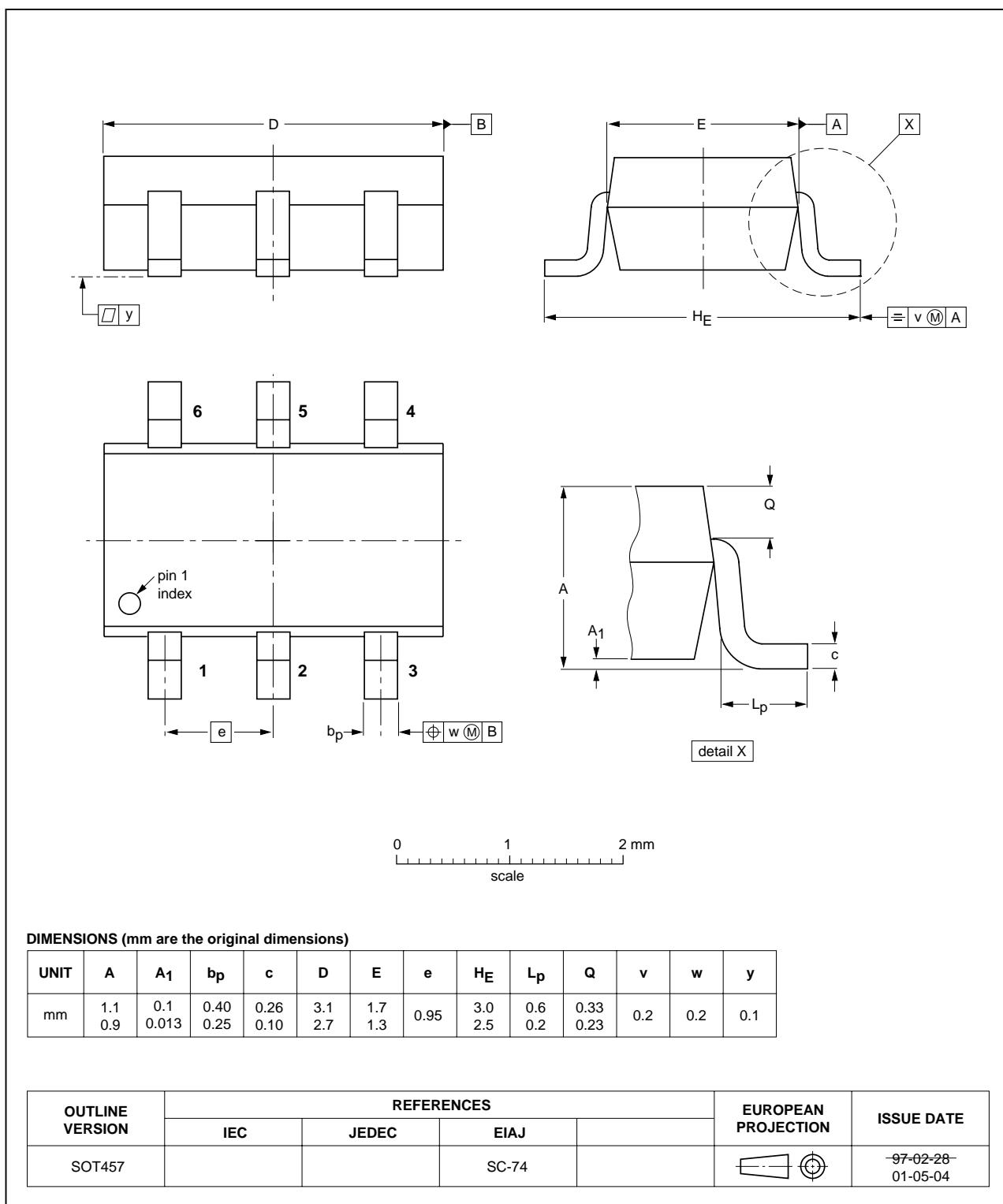
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ	SC-88		
SOT363						97-02-28

## Dual inverter

74LVC2G04

Plastic surface mounted package; 6 leads

SOT457

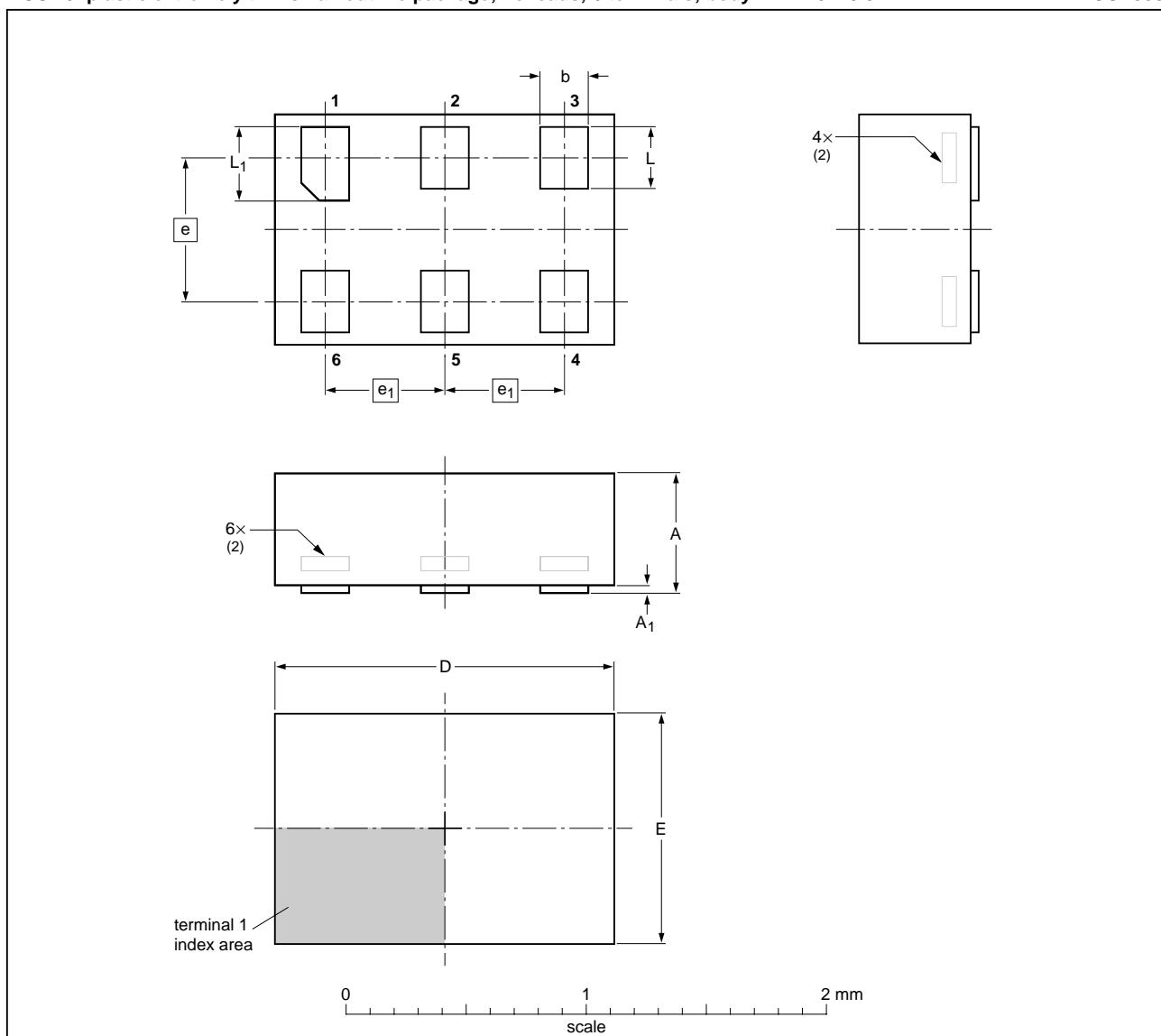


## Dual inverter

74LVC2G04

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886



DIMENSIONS (mm are the original dimensions)

UNIT	$A^{(1)}$ max	$A_1$ max	b	D	E	e	$e_1$	L	$L_1$
mm	0.5	0.04	0.25 0.17	1.5 1.4	1.05 0.95	0.6	0.5	0.35 0.27	0.40 0.32

## Notes

1. Including plating thickness.
2. Can be visible in some manufacturing processes.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT886		MO-252				04-07-15 04-07-22

## Dual inverter

74LVC2G04

## DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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